

DO NOT ENTER: /W.L./

AMENDMENT UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
GROUP 2814
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q79703

Hisayuki MIKI, et al.

Appln. No.: 10/586,849

Group Art Unit: 2814

Confirmation No.: 3462

Examiner: Wai Sing LOUIE

Filed: July 20, 2006

For: GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR MULTILAYER STRUCTURE AND PRODUCTION METHOD THEREOF

AMENDMENT UNDER 37 C.F.R. § 1.116

MAIL STOP AF

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated December 4, 2008, please amend the above-identified application as follows on the accompanying pages.

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